STTH6006W

Turbo 2 ultrafast - high voltage rectifier

Table 1. Main product characteristics

I _{F(AV)}	60 A
V _{RRM}	600 V
T _j	175° C
V _F (typ)	1.1 V
t _{rr} (max)	60 ns

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces conduction and switching losses



The STTH6006W uses ST Turbo 2 600 V technology. This device is specially suited for use in switching power supplies, and industrial applications. The V_{F} / T_{rr} trade-off has been specially established to increase the performance in welding applications.

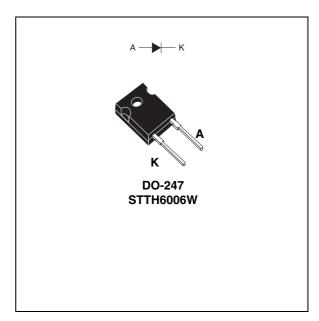


Table 2. Order code

Part number	Marking	
STTH6006W	STTH6006W	

Table 3. Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)

Symbol	Pa	Parameter		
V _{RRM}	Repetitive peak reverse voltage		600	V
I _{F(RMS)}	RMS forward current	90	Α	
I _{F(AV)}	Average forward current, $\delta = 0.5$	T _c = 95° C	60	Α
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal	400	Α
T _{stg}	Storage temperature range	-65 to + 175	°C	
T _j	Maximum operating junction tempera	175	°C	

^{1.} $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ to avoid thermal runaway for a diode on its own heatsink

Characteristics STTH6006W

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Table 4. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	0.75	°C/W

Table 5. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	I _R ⁽¹⁾ Reverse leakage current		V V			50	μA
'R`	IR. A neverse leakage current	T _j = 125° C	$V_R = V_{RRM}$		160	1600	μΛ
V _F ⁽²⁾ Forward voltage drop		T _j = 25° C	I _F = 60 A			1.85	V
v _E ··· Forward voltage drop	T _j = 150° C	1F = 00 A		1.10	1.40	V	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2$ %

To evaluate the conduction losses use the following equation:

$$P = 1.07 \times I_{F(AV)} + 0.006 I_{F}^{2}_{(RMS)}$$

Table 6. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
+	Rayarsa racayary tima	$I_F = 0.5 \text{ A}, I_{rr} = 0.25 \text{ A}, I_R = 1 \text{ A},$ $T_j = 25^{\circ} \text{ C}$			60	ns
t _{rr} Reverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		60	85	113	
I _{RM}	Reverse recovery current	$I_F = 60 \text{ A}, dI_F/dt = -100 \text{ A/}\mu\text{s}, \ V_R = 400 \text{ V}, T_j = 150^{\circ} \text{ C}$		10.5	14	
t _{fr}	Forward recovery time	$I_F = 60 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$			500	ns
V _{FP}	Forward recovery voltage	$I_F = 60 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$		3		٧

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

STTH6006W Characteristics

Figure 1. Conduction losses versus average current

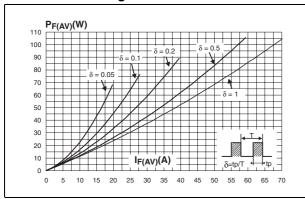


Figure 2. Forward voltage drop versus forward current

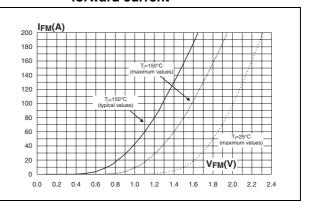


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

pulse duration

1.0

2th(j-c)/Rth(j-c)

0.9

Single pulse

0.7

0.6

0.5

0.4

0.3

0.2

0.1

1.E-03

1.E-02

1.E-01

1.E+00

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values)

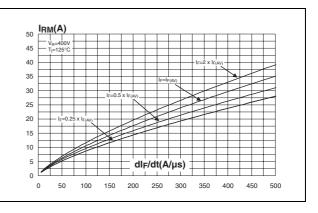


Figure 5. Reverse recovery time versus dl_F/dt (typical values)

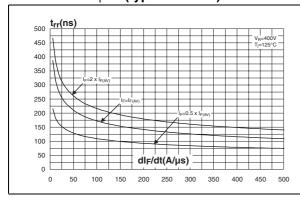
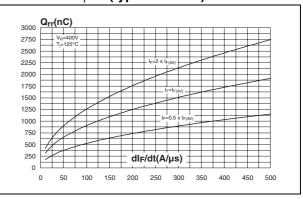


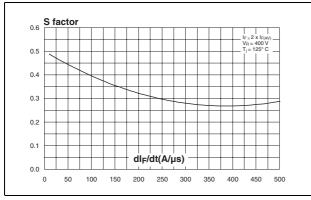
Figure 6. Reverse recovery charges versus dl₌/dt (typical values)



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Figure 7. Softness factor versus dl_F/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature



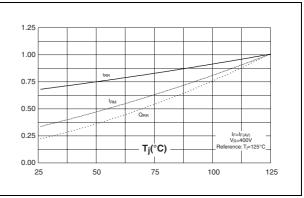
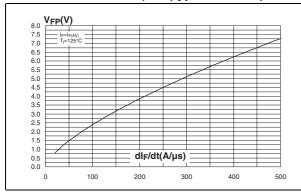


Figure 9. Transient peak forward voltage versus dl_E/dt (typical values)

Figure 10. Forward recovery time versus dl_F/dt (typical values)



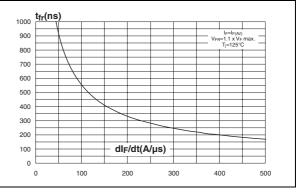
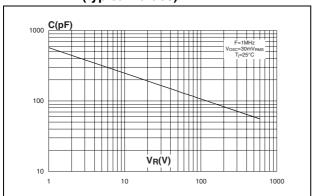


Figure 11. Junction capacitance versus reverse voltage applied (typical values)



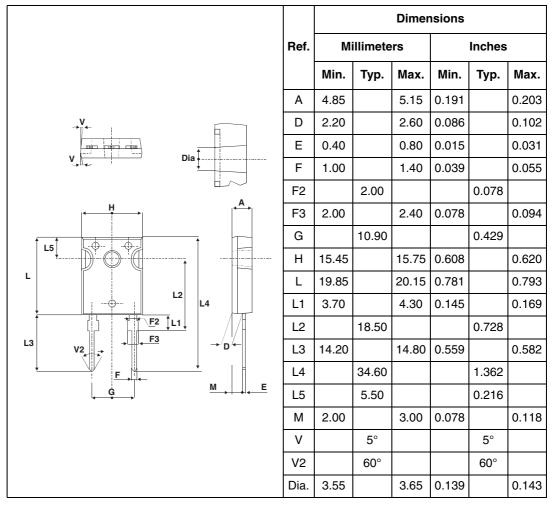
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2 Package mechanical data

Epoxy meets UL94, V0

Cooling method: by conduction (C)
 Recommended torque value: 0.80 Nm
 Maximum torque value: 1.0 Nm

Table 7. DO-247 dimensions



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Ordering information STTH6006W

3 Ordering information

 Table 8.
 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH6006W	STTH6006W	DO-247	4.40 g	30	Tube

4 Revision history

Table 9.Revision history

Date	Revision	Changes
18-May-2006	1	First issue.
11-Jul-2007	2	Reformatted to current standards. Updated <i>Table 7</i> .

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